ABSORPTION LINES IN TRANSITION METAL COMPLEXES

IKUJI TSUJIKAWA

*Department of Chemistry, Faculty of Science,
Kyoto University, Kyoto, Japan*

ABSTRACT

For the past sixteen years, the absorption lines in complexes of the iron group have been investigated on the basis of ligand field theory. These studies, and in particular our recent studies involving chromium complexes, are reviewed.

INTRODUCTION

The absorption spectra of complexes of the iron group consist of absorption bands and absorption lines. Whereas extensive studies of the absorption bands have been made since Werner's day, the absorption lines have so far attracted only a little attention and have been studied only by a few individual workers since about 1930. In 1954, the ligand field theory was developed by Tanabe and Sugano¹, and by Orgel², based on the crystal field theory of Bethe. Since then, the absorption lines as well as the absorption bands have been investigated from the standpoint of ligand field theory. The optical anisotropy and the Zeeman effect of absorption lines in ruby were successfully analysed in 1958^{3,4}. Since then, the absorption lines arising from ions of the iron group in solids have been of considerable interest.

Of course, the absorption lines appear to be more capable of resolution than do the absorption bands. This makes it relatively easy to obtain initial splittings, g values, multiplicities etc. of excited states, as well as the intensities of transition components. It also makes it possible to assign excited states and to deduce transition characters, besides leading to an understanding of the detailed character of complexes.

I shall first explain briefly the mechanisms of transitions and review results obtained from experiments, and then survey the studies of absorption lines in chromium complexes in our laboratory. They concern (1) excited states and transition characters from the standpoint of the ligand field theory, (2) thermal behaviour of the absorption lines, and (3) the electric effect of the environment on the absorption lines.

MECHANISMS OF TRANSITIONS

The level of an electron in the partly filled shell of transition metal complexes, namely that of a single d electron, splits into the t_{2g} and e_g levels in

the ligand field of cubic symmetry O_h . The ligand field parameter Δ is defined as the energy between these two levels. The partly filled shell represents electronic configurations $t_{2g}^{n'} e_g^{n-n'}$ ($1 \leq n \leq 9$). If the Coulomb interaction is taken into account, $5F$ multiplets also split, like $5F$ multiplets of d^n configurations in the free ion. Here Γ represents one of the irreducible representations of O_h , namely A_{1g} , A_{2g} , E_g , T_{1g} or T_{2g} . If angular dependences of the molecular orbitals t_{2g} and e_g are approximated as those of the d orbitals in the free ion, the energies of the multiplets are expressed with the Slater integrals F_0 , F_2 and F_4 or with Racah's parameters $A \equiv F_0 - 49 F_4$, $B \equiv F_2 - 5 F_4$ and $C \equiv 35 F_4$. F_0 or A is independent of the relative energies of the multiplets and the relation $C \approx 4B$ holds. It follows immediately that the relative energies of the multiplets can be expressed only with Δ and B . The absorption bands correspond to transitions in which one electron is promoted from the t_{2g} orbital to the e_g one, expressed as $t_{2g}^{n'} e_g^{n-n'} 5F \rightarrow t_{2g}^{n'-1} e_g^{n-n'+1} 5F'$ and Δ contributes to transition energies¹. Δ has a width of about 3000 cm^{-1} due to the zero point vibration of a complex. On the other hand, the absorption lines correspond to transitions between states with the same electronic configurations but with total spins different by one unit, expressed as $t_{2g}^{n'} e_g^{n-n'} 5F \rightarrow t_{2g}^{n'} e_g^{n-n'} S \pm 1F'$. There is no electronic excitation $t_{2g} \rightarrow e_g$, so that Δ does not contribute to the transition energies. The absorption lines are spin forbidden, because the transition moment of an electric dipole or of a magnetic dipole has no matrix elements between states with different spin multiplicities. In addition, absorption lines as well as the absorption bands, are forbidden by the Laporte rule, because states from d^n configurations have even parity. Hence the absorption lines are doubly forbidden by spin and parity.

The spin orbit interaction V_{so} is required to mix states with different spin multiplicities. It leads to the situation that spin forbidden transitions are to be allowed. The spin orbit interaction has matrix elements between states with total spins differing by one unit. The wavefunction for a state ($\alpha_o \Gamma_T$) is

$$\Phi(\alpha_o \Gamma_T) = a \Phi_0(\alpha 5F, \Gamma_T) + \sum_i b_i \Phi_i(\alpha' S \pm 1F', \Gamma_T) \quad (1)$$

where Γ_T is the irreducible representation of $S \times \Gamma$. Equation 1 shows that states with the same Γ_T mix only with each other. The coefficient b_i is given by perturbation theory as

$$b_i = \frac{(\Phi_i | V_{so} | \Phi_0)}{E(\Phi_i) - E(\Phi_0)} \quad (2)$$

Generally speaking, a is nearly equal to 1, and b_i has an order of magnitude of the multiplet width divided by the energy difference between different multiplets. In the case of iron group ions, the multiplet width is about 100 cm^{-1} and the energy between different multiplets about 3000 cm^{-1} . Then, the b_i is crudely estimated as 3×10^{-2} .

The mechanisms for introducing parity-forbidden transitions are explained below:

(1) There is the electric dipole transition due to orbital deformations by a

stress of the crystal field, in other words, due to: (a) an odd parity crystal field arising from thermal vibrations of the crystal, V_{ov} . A transition allowed by this mechanism is called a vibronically allowed one; (b) a hemihedral crystal field V_{hem} in the absence of the inversion centre of the crystal field, still at equilibrium positions of atoms.

2. There is the magnetic dipole transition. The magnetic dipole is an axial vector which has even parity. It follows that transitions between states with even parity are allowed by the magnetic dipole. Similarly, an electric quadrupole transition is also possible but has not been found experimentally.

We shall estimate an order of magnitude of the oscillator strength, f , f is related to the absorbent coefficient, $K(\nu)$

$$f = (mc/\pi Ne^2) \int K(\nu) d\nu \quad (3)$$

where N is the number of absorption centres per cm^3 and ν is the frequency.

Now consider the case 1(a). The crystal field $V(\vec{r}, \vec{Q})$ is expanded in a power series of $Q(\gamma, m_\gamma)$. Here $\vec{r}$ is the electronic coordinate and $Q(\gamma, m_\gamma)$ the normal coordinate of the γm_γ -th mode lattice vibration, namely,

$$V(\vec{r}, \vec{Q}) = V_0(\vec{r}) + \sum_{\gamma m_\gamma} V(\gamma m_\gamma) Q(\gamma m_\gamma) + \dots \quad (4)$$

and

$$\vec{r} V(\gamma m_\gamma) = \left(\frac{\partial V}{\partial Q(\gamma m_\gamma)} \right)_{Q(\gamma m_\gamma)=0} \quad (5)$$

where $V_0(r)$ is the crystal field at the nuclear equilibrium positions. Now we assume that the d electrons interact strongly only with vibrations of the complex ion. The second term of equation 4 mainly contributes to V_{ov} and then V_{ov} is given by

$$V_{ov} = \sum_{\gamma m_\gamma} V(\gamma m_\gamma) Q(\gamma m_\gamma) \quad (6)$$

where γ represents odd type vibrational modes of the complex ion. They are f_{1u}^a , f_{1u}^b and f_{2u} if we deal with the case of the regular octahedral complex. The magnitude of V_{ov} is crudely estimated as follows

$$V_{ov} \simeq (\partial R / \bar{r}) V_0 \quad (7)$$

where ∂R is the zero point amplitude of vibration, and $\bar{r}$ the mean of r . ∂R is obtained from the relation

$$2\pi\mu\nu^2(\partial R)^2 = \frac{1}{2}h\nu \quad (8)$$

where μ is the effective mass of the complex. If ν is taken as 10^{13} s^{-1} and μ as $4 \times 10^{-23} \text{ g}$, ∂R may be estimated as about 10^{-9} cm . If $\bar{r}$ is taken as 10^{-8} cm and V_0 as 10^4 cm^{-1} , V_{ov} turns out to about 10^3 cm^{-1} . An even parity wavefunction Φ_g is contaminated with an odd parity wavefunction Φ_u due to V_{ov} and then the wavefunction is written including vibrational wavefunctions χ_n and $\chi_{\bar{n}}$ as

$$\Phi\chi_n = c\Phi_g\chi_n + \sum_i d_i\Phi_u \cdot i\chi_{\bar{n}} \quad (9)$$

The coefficient c is commonly nearly equal to 1 and

$$d_i = (\Phi_g \chi_n | V_{ov} | \Phi_u, i \chi_{\bar{n}}) / \{E(\Phi_g) - E(\Phi_u, i)\} \quad (10)$$

where χ_n and $\chi_{\bar{n}}$ have quantum numbers differing by only one unit. In the absorption spectra at low temperatures, χ_n is the state with all the quantum numbers equal to 0 in all vibrational modes and $\chi_{\bar{n}}$ is the one with the quantum number promoted to 1 in any one of the odd type vibrational modes. If V_{ov} is taken as 10^3 cm^{-1} and $E(\Phi_u) - E(\Phi_g)$ as 10^5 cm^{-1} , the degree of contamination, d will be about 10^{-2} . The oscillator strength of the allowed electric dipole transition, f_{allow} , is expressed as

$$f_{\text{allow}} \simeq (8\pi^2 m / 3h) \nu \bar{r}^2 \quad (11)$$

and its order of magnitude is 1. Therefore f in this case, f_{elec} , is given by

$$f_{\text{elec}} = b^2 \times d^2 \times f_{\text{allow}} \simeq 10^{-7} \quad (12)$$

In the absorption band b^2 in equation 1 can be omitted and it follows that f is estimated as about 10^{-4} .

In the case 1(b) the first term of equation 1 can be considered as

$$V_0(\vec{r}) = V_{\text{hol}}(\vec{r}) + V_{\text{hem}}(\vec{r}) \quad (13)$$

where V_{hol} is the even parity crystal field which causes states to split as already mentioned. V_{hem} does not contribute to splittings between states, nor to the thermal and magnetic properties of the substance. Hence, it is difficult to estimate its magnitude empirically, but roughly speaking V_{hem} might have the same order of magnitude as V_{ov} . Thus in this case, the oscillator strength might have the order of magnitude of f_{elec} obtained in equation 12.

The oscillator strength in the case 2: f_{mag} is given by

$$f_{\text{mag}} = b^2 \times (8\pi^2 m / 3he^2) \nu M^2 \simeq 4 \times 10^{-9} \quad (14)$$

where M is the matrix element of the magnetic dipole between the ground and excited states and its magnitude is about one Bohr magneton.

The estimation of oscillator strengths outlined above is so crude that an error by a factor of 10 to 10^2 may enter. However, it is likely that the electric dipole transition is generally more intense than the magnetic dipole one.

INFORMATION OBTAINED FROM SPECTROSCOPIC MEASUREMENTS

(a) Absorption spectrum

Transition energies, absorption intensities and absorption widths are obtained from measurements of absorption spectra. Generally, absorption lines shift to shorter wavelengths and become sharp with decreasing temperature. It is desirable to measure absorption lines at low temperatures for better resolution.

(b) Optical anisotropy

Optical anisotropy exists in all crystals except those of the cubic system. Whether transitions are caused by the electric dipole or by the magnetic

dipole can be experimentally determined without any theoretical analysis. The case of uniaxial crystals will be explained.

As shown in *Figure 1*, let incident linearly polarized light be parallel and perpendicular to the optic axis. If we neglect a small anisotropy on the plane perpendicular to the optic axis, cases (a) and (b) give the same situation that both the electric and magnetic vectors of the incident light, i.e. $\vec{E}$ and $\vec{H}$ are perpendicular to the optic axis. In cases (c) and (d), one of E and H is perpendicular and the other parallel to the optic axis. Now measure the absorption lines with the polarized light. If the same spectrum is obtained in cases (a) and (c) [or in the cases (a) and (d)] where $\vec{E}$ (or $\vec{H}$) is commonly perpendicular to the optic axis, transitions can be regarded as the electric dipole (or magnetic dipole) transitions.

Figure 1. Relation between the optic axis, C , the incident linearly polarized light, L , the electric vector of the incident light, $\vec{E}$, and its magnetic vector, $\vec{H}$.

(c) The Zeeman effect

The g values and multiplicities of excited states and intensities of Zeeman components are obtained. In the case of the cubic system, it can be determined experimentally from the anisotropy of the Zeeman effect whether transitions are caused by the electric or magnetic dipole. Multiplicities of excited states are determined by measurements of Zeeman effect in the condition $\mu_B H_0 > kT$ where H_0 denotes a magnetic field. An example is shown in *Figure 2*. We assume that g values of both the ground and excited states are 2.0 and that the ground state is a quartet. In the condition $\mu_B H_0 > kT$, populations on higher Zeeman sublevels of the ground state are much smaller than those on lower ones, according to the Boltzmann distribution law. If the excited state is also a quartet, the intensity of the centre Zeeman component does not decrease. On the contrary, if the excited state is a doublet, the intensity of the centre Zeeman component will decrease considerably.

The above is what can be known from experiments alone; to assign excited states and to obtain information about a lower symmetry crystal field and

Figure 2. Transition diagram of Zeeman effect and model diagram of Zeeman pattern.

the spin orbit coupling, theoretical analyses are required on the intensities, anisotropies, Zeeman effect etc. In the case of absorption bands, however, it might be difficult to obtain these details due to their lower resolution.

RESEARCH ON EXCITED STATES AND TRANSITION CHARACTERS

The main iron group octahedral complexes which have been studied are reviewed in Table 1. The ruby $\text{Al}_2\text{O}_3:\text{Cr}^{3+}$, $\text{MgO}:\text{Cr}^{3+}$ and $\text{Al}_2\text{O}_3:\text{V}^{3+}$ are not complexes, but analyses of absorption lines in them were successful on the basis of ligand field theory, so they are shown here together. Mention should be made of the studies of tetrahedral cobaltous compounds by Pelletier-Allard³⁴ and by Ferguson³⁵. Complexes of the Cr^{3+} and Mn^{2+} ions were widely investigated because of absorption widths smaller than 5 cm^{-1} . Complexes of the Cr^{2+} , Fe^{3+} and Fe^{2+} ions can be expected to have absorption lines in view of their electronic configurations, but they have been little studied.

Studies of absorption lines in iron group complexes have been limited

Table 1. The main iron group octahedral complexes studied. M in the formula of chromium alum denotes monovalent ions, E and H denote the electric and magnetic dipole transitions respectively, and Z means that the measurement of Zeeman effect was made.

Ions	Substances	Transitions	Transition energies	Wave No. (cm^{-1})	Remarks	References
V^{3+} (t_{2g}^3)	$Al_2O_3 \cdot V^{3+}$	${}^3T_1 \rightarrow {}^1E, {}^1T_2$ $\rightarrow {}^1A_1$	$6B + 2C$ $15B + 5C$	10000 21000	EZ EZ	5-7
Cr^{3+} (t_{2g}^3)	$Al_2O_3 \cdot Cr^{3+}$ $MgO \cdot Cr^{3+}$ $MCr(SO_4)_2 \cdot 12H_2O$ $Cr(NH_2)_3 \cdot Cr(SO_4)_2 \cdot 6H_2O$	${}^4A_2 \rightarrow {}^2E, {}^2T_1$ ${}^4A_2 \rightarrow {}^2E$ ${}^4A_2 \rightarrow {}^2E$ ${}^4A_2 \rightarrow {}^2E, {}^2T_1$	$9B + 3C$	15000	EZ MZ MZ EZ	3, 4, 8-11 12, 13 6, 14-22 23-26
	$Al_2O_3 \cdot Cr^{3+}$ $MCr(SO_4)_2 \cdot 12H_2O$ $Cr(NH_2)_3 \cdot Cr(SO_4)_2 \cdot 6H_2O$	${}^4A_2 \rightarrow {}^2T_2$ ${}^4A_2 \rightarrow {}^2T_2$ ${}^4A_2 \rightarrow {}^2T_2$	$15B + 5C$	21000	EZ	3, 4, 27, 28 16
Mn^{2+} ($t_{2g}^5 e_g^2$)	$MnSiF_6 \cdot 6H_2O$ $MnCl_2 \cdot 2MgCl_2 \cdot 12H_2O$ $CoCl_2 \cdot 6H_2O$	${}^6A_1 \rightarrow {}^4E, {}^4A_1$ ${}^4T_1 \rightarrow {}^2T_1$ $\rightarrow {}^2T_2$	$10B + 5C$ $4B + 3C$ $14B + 4C - \{(4B + C)^2 + 100B^2\}^{\frac{1}{2}}$	25000 16000 19000	MZ EZ E	29, 30 31
		$\rightarrow {}^2T_1$	$12B + 3C$	25000	E	32
Ni^{2+} ($t_{2g}^6 e_g^2$)	$NiSiF_6 \cdot 6H_2O$	${}^3A_2 \rightarrow {}^1E$ $\rightarrow {}^1A_1$	$8B + 2C$ $16B + 4C$	18000 25000	E E	33

owing to several experimental restrictions: (1) Crystals of sufficient dimension are needed to permit measurement. (2) Crystals must maintain transparency without any damage at low temperatures. (3) Higher magnetic fields than usual (30 kOe) are required to measure the Zeeman effect of absorption lines of widths larger than 2 cm^{-1} . (4) It may happen that liquid helium or hydrogen, a strong magnetic field and a high resolution spectrograph are all needed in the same experiment.

(a) **Thallium chromium alum**, $\text{TlCr}(\text{SO}_4)_2 \cdot 12\text{H}_2\text{O}$

Alums belong to the cubic system and the unit cell contains four molecules. Each Cr^{3+} ion is surrounded by six water molecules with a nearly regular octahedral arrangement. The Cr^{3+} ions are placed along the four body diagonals of the unit cell and exposed to the crystal field with the trigonal symmetry C_{3i} . Thallium chromium alum has two absorption lines, $R_1: 14943\text{ cm}^{-1}$ and $R_2: 14945\text{ cm}^{-1}$. Measurements of absorption lines were made photographically by use of a grating spectrograph with a dispersion of $2.5\text{ \AA/mm}$ in the first order at low temperatures down to 1.3°K . For the measurement of the Zeeman effect, a magnetic field of 27 kOe was applied parallel to the cubic axis C_2 , the body diagonal C_3 and face diagonal C_0 of the crystal. The results are shown in *Figure 3*. Anisotropy, not observed in the absence of magnetic field, is produced by applying the magnetic field. Zeeman components of the longer wavelength side almost disappear at 1.3°K because of the reason already mentioned. *Figure 4* shows the Zeeman effect with three directions of the incident light L by use of the magnetic field parallel to the C_0 axis. The three spectra with the same direction of H but with different direction of E are identical. It follows immediately that the transitions are caused by the magnetic dipole. This is reasonable because the site symmetry of the Cr^{3+} ion has an inversion centre.

Now we shall analyse the g tensors of the excited states and Zeeman patterns of the R lines, and give predicted Zeeman patterns. The Hamiltonian for the Cr^{3+} ion in chromium alum is given by

$$H = H_0 + H' \quad (15)$$

and

$$H' = V_{\text{trig}} + V_{\text{so}} \quad (16)$$

where H_0 is the Hamiltonian for the cubic field, V_{trig} the trigonal field and V_{so} the spin-orbit interaction. Here H' may be considered as a small perturbation. The group theory, in which both the crystal symmetry and the time-reversal symmetry are taken into account, leads to the effective Hamiltonian for the excited state 2E as follows.

$$H_{\text{eff}} = \lambda S_z T(A_2) \quad (17)$$

where λ is a parameter to be determined empirically and $T(A_2)$ is an orbital

ABSORPTION LINES IN TRANSITION METAL COMPLEXES

Figure 3. Zeeman patterns of the R lines for various directions of the magnetic field at liquid helium temperatures in thallium chromium alum.

Figure 4. Zeeman patterns of the R lines for various directions of the incident light with $H_0 \parallel C_0$ at 4.2°K in thallium chromium alum.

operator. The eigenvalues and corresponding eigenfunctions are:

$$\begin{aligned} E_2 &= \frac{1}{2}\lambda, & \begin{cases} 2\bar{A} & \Phi(^2E, \frac{1}{2}u_+) \\ & \Phi(^2E, -\frac{1}{2}u_-) \end{cases} \\ E_1 &= -\frac{1}{2}\lambda, & \begin{cases} \bar{E} & \Phi(^2E, \frac{1}{2}u_-) \\ & \Phi(^2E, -\frac{1}{2}u_+) \end{cases} \end{aligned} \quad (18)$$

where $2\bar{A}$ and $\bar{E}$ are the two-valued representations of the C_{3i} . According to the second order perturbation in H' in which the intermediate states are restricted to states in the configuration t_{2g}^3 , we find

$$\lambda(^2E) = 4K\zeta / \{E(^2E) - E(^2T_2)\} \quad (19)$$

where

$$K = \langle t_{2x\pm} | V_{\text{trig}} | t_{2x\pm} \rangle \quad (20)$$

and

$$\zeta = -2\langle t_{2\frac{1}{2}x_+} | V_{\text{so}} | t_{2\frac{1}{2}x_+} \rangle \quad (21)$$

Equation 19 leads to the trigonal field parameter, $K = -25 \text{ cm}^{-1}$, where the spin-orbit coupling parameter, $\zeta = 140 \text{ cm}^{-1}$ and $E(^2E) - E(^2T_2) = -7000 \text{ cm}^{-1}$ are used.

In order to assign the final states of the transition, the magnetic dipole strengths are calculated for the transitions from the ground state 4A_2 to the Kramers doublets $2\bar{A}$ and $\bar{E}$ of the 2E state. The magnetic dipole strength polarized in γ_0 is given by

$$\begin{aligned} S_{\text{mag}}(^4A_2M_s e_2 \rightarrow ^2E\bar{M}_s\bar{M} : \gamma_0) \\ = \frac{\mu_B^2 |\sum_M \langle ^4A_2M_s e_2 | M(\gamma_0) | ^4T_2M_sM \rangle \langle ^4T_2M_sM | V_{\text{so}} | ^2E\bar{M}_s\bar{M} \rangle|^2}{[E(^4T_2) - E(^2E)]^2} \end{aligned}$$

where $\bar{M}$ is $-\Sigma_i(l_i + 2S_i)$ and γ_0 is a component of $\bar{M}$.

The angular dependence of g values of the $\bar{E}$ and $2\bar{A}$ states is shown in Figure 5. If we ignore the difference between the g values of the $\bar{E}$ and $2\bar{A}$ states, the angular dependence of g values becomes

$$g(R_1) = g(R_2) = [(\lambda + g_{\parallel}\mu_B H_{oz})^2 + (g_{\perp}\mu_B H_{ox})^2]^{\frac{1}{2}} / \mu_B H_0 \quad (23)$$

The calculated angular dependence agrees well with experimental results.

The experimental and calculated Zeeman patterns in the case of $H_0 \parallel C_3$ are shown in Figure 6. The calculated Zeeman patterns with $\lambda > 0$ agree with the experimental ones. It follows immediately that the R_1 and R_2 lines correspond to transitions to the $\bar{E}(^2E)$ and $2\bar{A}(^2E)$ states respectively.

When a magnetic field is applied along directions other than the trigonal axis, a contamination of spin components occurs through the perpendicular Zeeman terms. If the Zeeman energy exceeds the anisotropy energy, the crystal Paschen-Back effect occurs and the quantization axis of the excited state deviates from the trigonal axis. The experimental and calculated Zeeman

Figure 5. The angular dependence of g values of the excited states which are final levels of the transitions of the R_1 and R_2 lines in thallium chromium alum. θ is the angle between the direction of the magnetic field and the trigonal axis. The theoretical curves are set by using equation 23, with $\lambda = 2.0 \text{ cm}^{-1}$, $g_{\parallel} = 1.9$ and $g_{\perp} = 1.6$

Figure 6. Schematic representations of the experimental and calculated Zeeman patterns of the R lines with $H_0 \parallel C_3$ at 4.2°K in thallium chromium alum. The heights of the solid lines in the patterns represent the relative intensities of the Zeeman components.

ABSORPTION LINES IN TRANSITION METAL COMPLEXES

patterns in the case of $H_0 \parallel C_2$ are shown in *Figure 7*. In the middle pattern, the crystal Paschen-Back effect is ignored, i.e. it is assumed that $|\lambda| \gg |g_{\perp} \mu_B H_0|$. By taking into account the Paschen-Back effect, the agreement between the experimental and calculated Zeeman patterns becomes good.

Figure 7. Schematic representations of the experimental and calculated Zeeman patterns of the R lines with $H_0 \parallel C_2$ at 4.2°K in thallium chromium alum.

The Paschen-Back limit pattern could be photographed with a spectrograph with the dispersion of 15 Å/mm by use of the pulsed magnetic field of 220 kOe as shown in *Figure 8*. The R_1 and R_2 lines cannot be resolved in the absence of magnetic field due to the low resolution of the spectrograph. The side components shift linearly with the field strength, and the effective splitting factor for the side components is isotropic and about four. When the Zeeman energy exceeds the anisotropy energy of the excited state spin, the excited state spin is quantized to the direction of the magnetic field as well as ground state spin, therefore the nearly degenerate excited states are expected to behave as a free spin doublet. The calculated Paschen-Back patterns with the experimental ones are shown in *Figure 9*. The agreement between them is good. Then it is ascertained that the R_1 and R_2 lines correspond to the magnetic dipole transition from the ground state 4A_2 to the excited state 2E .

(b) Caesium chromium alum $\text{CsCr}(\text{SO}_4)_2 \cdot 12\text{H}_2\text{O}$

Caesium chromium alum has a single absorption line (R : 14479 cm^{-1}) in the red region. A study of the R line was made in a similar way to that of

Figure 8. Paschen-Back limit patterns formed by applying the pulsed magnetic field of 220 kOe with $H_0 \parallel C_2$ and with $H_0 \parallel C_3$ at 77°K in thallium chromium alum.

thallium chromium alum. Anisotropic Zeeman patterns indicate that the R line corresponds to the transition caused by the magnetic dipole. The experimental and calculated Zeeman patterns are shown in *Figures 10 and 11*. In the case of $H_0 \parallel C_2$, the calculated patterns for the transition to the $\bar{E}(^2E)$ state coincide with those for the transition to the $2\bar{A}(^2E)$ state and they agree with the experimental patterns. Other calculated patterns obtained, assuming that a final state is a split component of the 2T_1 state do not agree with the experimental patterns. In the case of $H_0 \parallel C_3$, the calculated Zeeman patterns for the transition to the $\bar{E}(^2E)$ state are different from those for the transition to the $2\bar{A}(^2E)$ state and the former agree well with the experimental patterns. Therefore, the R line may correspond to the transition from the ground state 4A_2 to the excited state $\bar{E}(^2E)$. The other transition to the $2\bar{A}(^2E)$ state is not found; the reason is not clear. But the splitting between the $2\bar{A}$ and $\bar{E}$ states must be much larger than 3.5 cm^{-1} , because the Zeeman components split linearly and the g values of the $\bar{E}$ state are anisotropic with magnetic fields up to 27 kOe.

ABSORPTION LINES IN TRANSITION METAL COMPLEXES

Figure 9. Experimental and theoretical Paschen-Back patterns of the R lines by applying high magnetic fields with $H_0 \parallel C_2$ and with $H_0 \parallel C_3$ at 77°K in thallium chromium alum.

Figure 10. Schematic representations of the experimental and calculated Zeeman patterns of the R line with $H_0 \parallel C_3$ at $T = 20^\circ K, 4.2^\circ K$ and $1.3^\circ K$ in caesium chromium alum

Figure 11. Schematic representations of the experimental and calculated Zeeman patterns of the R line with $H_0 \parallel C_2$ at $T = 20^\circ\text{K}$, 4.2°K and 1.3°K in caesium chromium alum.

RESEARCH ON THE THERMAL BROADENING AND THERMAL SHIFT OF ABSORPTION LINES

The study of the width, shape and position of absorption lines has not advanced in comparison with that of resonance lines of e.s.r. or n.m.r. In the case of iron group complexes, this aspect has not been investigated. We shall discuss the thermal behaviour of the R lines in thallium chromium alum. The magnitude of the magnetic dipole interaction in chromium alum has been estimated to be as small as 10^{-2} cm^{-1} . In fact, the Zeeman patterns of the R lines can be well explained regardless of the magnetic dipole interaction. We might, therefore, at this stage, consider the Cr^{3+} ions as localized ions in a host crystal and apply a theory of the thermal broadening and shift of zero-phonon lines of impurity ions in a crystal by Di Bartolo³⁶.

Thermal broadening mechanisms for sharp zero-phonon lines are classified into the following types. (1) Lifetime broadening due to radiationless decay or excitation of an ion, which involves (a) one phonon process, (b) multi-phonon processes and (c) Raman relaxation or excitation processes. (2) Lifetime broadening due to vibronic decay of an ion from an excited state, which involves one photon emission and one or multi-phonon absorption or emission. (3) Energy change due to adiabatic variation of crystal field, which concerns Raman scattering of phonons by an ion in an excited state. The ion remains in the same electronic state by phonon scattering. The

temperature dependent width of an ionic level is expressed as follows, in which the Debye phonon state density is assumed.

$$\Delta W(\text{cm}^{-1}) = \alpha \left(\frac{T}{T_D} \right)^7 \int_0^{T_D/T} \frac{x^6 e^x}{(e^x - 1)^2} dx + \frac{1}{C} \sum_{j < i} \beta_{ij} \left(\frac{\exp(\Delta E_{ij}/kT)}{\exp\{\Delta E_{ij}/kT\} - 1} \right) + \frac{1}{C} \sum_{j > i} \beta_{ij} \left(\frac{1}{\exp\{\Delta E_{ij}/kT\} - 1} \right) \quad (24)$$

where

$$\alpha = \frac{1}{C} \frac{9}{2\pi^3 \rho^2 v^{10}} \left(\frac{kT_D}{\hbar} \right)^7 \left| \langle \psi_f^{el} | V_2 | \psi_i^{el} \rangle \right. \\ \left. + \sum_i \frac{\langle \psi_f^{el} | V_1 | \psi_i^{el} \rangle \langle \psi_i^{el} | V_1 | \psi_i^{el} \rangle}{E_i^{el} - E_i^{el}} \right|^2 \quad (25)$$

and

$$\beta_{ij} = \frac{3\omega_{ij}^2}{2\pi\rho v^5 \hbar} \langle \psi_i^{el} | V_1 | \psi_j^{el} \rangle^2 \quad (26)$$

where T_D is the Debye temperature, ρ the density of crystal, v the mean sound velocity in the crystal, and V_1 and V_2 are electron phonon coupling operators. In equation 24, the first term concerns the Raman processes and the second and third terms concern one phonon excitations and relaxation processes respectively. All the processes in equation 24 contribute to a homogeneous broadening of the linewidth and predict a Lorentzian shape. The energy levels of an ion in the crystal shift with temperatures through the ion-lattice vibration interaction. The shift can be formulated in a similar form as the width of an ionic level.

The R lines were measured photoelectronically with a 'Spex Model 1800' spectrometer at temperatures between 77°K and 300°K. In *Figures 12* and *13*, experimental temperature dependences of the linewidth and of the shift are shown together with the calculated ones, and parameters are given for the best fit with experiments. The observed linewidth and shift are strongly dependent on temperature in the range between 77°K and 260°K respectively. These results are consistent with the two phonon Raman process model having the Debye temperature 120°K, which is not so far from $T_D = 80^\circ\text{K}$ obtained from a specific heat measurement. The coupling parameter β_{ij} is zero, meaning that the one phonon direct processes do not contribute to the linewidth. One of the reasons for $\beta_{ij} = 0$ is the small number of available phonons for a single phonon decay. The second reason is the weak electron-phonon coupling $\langle \psi_i^{el} | V_1 | \psi_j^{el} \rangle$, since wavefunctions of the two electronic states ψ_i^{el} and ψ_j^{el} corresponding to the Kramers doublets of the 2E state, are almost the same in a dominantly cubic crystal field. The

Figure 12. The temperature dependence of the halfwidth of the R_1 line under the assumption that those of the R_1 and R_2 lines are to show the same thermal broadening in thallium chromium alum

Figure 13. The temperature dependence of the lineshift of the R_1 line obtained from the same assumption as stated in Figure 12 in thallium chromium alum

width of the B lines in chromium alums is several times as great as that of the R lines. This may be due to the lifetime broadening of the B lines which is greater than that of the R lines, and is caused by the direct phonon processes. This results from the fact that the broad U band exists on the lower energy side of the B lines.

The Raman excitation and relaxation processes (1c) may contribute to the linewidth of the R lines as well as the Raman scattering process (3), but it is difficult to discriminate between the contributions of each, because the line broadening due to all the Raman processes shows the same temperature dependence.

Figure 14. The absorption coefficient curve of the R lines at 77°K compared with Lorentzian and Gaussian curves in thallium chromium alum

The line shape of the R_1 and R_2 lines at 77°K is compared with the Gaussian and Lorentzian shapes as shown in Figure 14. The line shape at 77°K , like the Lorentzian shape is due to the homogeneous broadening effects. In ruby or $\text{MgO}:\text{Cr}^{3+}$, the linewidth of the R lines at 77°K is dominantly caused by heterogeneous strains such as imperfection and dislocation which lead to the Gaussian shape. This difference may be ascribed to the low Debye temperature ($\sim 100^\circ\text{K}$) of alums and the high Debye temperature ($\sim 900^\circ\text{K}$) of ruby or $\text{MgO}:\text{Cr}^{3+}$. The specimen-dependent linewidth of the R lines at 4.2°K in thallium chromium alum may be caused by a microscopic crystal strain. After all, one Cr^{3+} ion in the crystal of alum might be considered as an ideal localized system in the sense that magnetic interactions can be disregarded.

RESEARCHES FOR THE EFFECT OF THE ENVIRONMENT ON THE ABSORPTION LINES

It is interesting to investigate the effect of the environment on the absorption lines, either electric or magnetic, from the standpoint of the research on phenomena which cannot be dealt with by the ligand field theory. First we investigated spectroscopically the magnetically ordered states, in other words, we studied absorption lines in the antiferromagnetic state of manganous chloride and bromide tetrahydrates³⁷ and in the ferrimagnetic state of manganous acetate tetrahydrate³⁸ and obtained information about the easy axis, the molecular field and the spin flop phenomenon. Since then, studies of the magnon sidebands (lines) in iron group compounds have been rapidly developed to make one of the most interesting fields of research in solid state physics. It might be also possible to find magnon sidelines in iron group complexes.

At the present time, in order to investigate the electric effect of the environment on the absorption lines, we are studying two absorption lines (R_1 : 14111 cm^{-1} , R_2 : 14131 cm^{-1}) of guanidine chromium sulphate hexahydrate $\text{C}(\text{NH}_2)_3\text{Cr}(\text{SO}_4)_2 \cdot 6\text{H}_2\text{O}$ which has a ferroelectric property^{25,26}. Crystals of this complex belongs to the trigonal system and the unit cell contains three molecules. Cr^{3+} ions are surrounded by a distorted octahedron of six water molecules, and one third of the Cr^{3+} ions are in the C_{3v} and two thirds are in the C_3 site symmetries.

By consideration of the optical anisotropy of the R lines, it can be concluded that the transitions are caused by the electric dipole. This is reasonable because both the two site symmetries of Cr^{3+} ions have no centre of inversion. But analyses of Zeeman patterns of the R lines are not successful, and then we suppose that the effect of the environment may be significant. The analyses of the g values of the excited states suggest that both the R_1 and R_2 lines correspond to the transition from the ground state 4A_2 to the excited state $\bar{E}(^2E)$ and each of the R_1 and R_2 lines attributes to each of the C_3 and C_{3v} symmetry sites in accordance with a conclusion made by Martin-Bruntière and Couture²³ and by Camassei and Forster²⁴.

An interesting phenomenon was found during the dilution of Cr^{3+} ions by Al^{3+} ions²⁵; both the R lines split into seven components as shown in *Figure 15*. Each split component shifts linearly with concentration of Cr^{3+} ions and splittings between neighbouring components are nearly constant at 6 cm^{-1} . Absorption intensity of each component varies with concentration and has a maximum at a certain concentration.

To explain the phenomenon, one may consider a model which consists of a central $[\text{Cr}(\text{H}_2\text{O})_6]^{3+}$ ion and six nearest neighbours of $[\text{M}(\text{H}_2\text{O})_6]^{3+}$ ions (M is Cr or Al), equidistant from the central ion in the plane normal to the trigonal axis C_3 , as shown in *Figure 16*. The electric field strength at the central ion produced by the nearest neighbour $[\text{Cr}(\text{H}_2\text{O})_6]^{3+}$ ion must be different from that produced by a nearest neighbour $[\text{Al}(\text{H}_2\text{O})_6]^{3+}$ ion and then seven different arrangements exist depending on the number of $[\text{Cr}(\text{H}_2\text{O})_6]^{3+}$ ions in the six nearest neighbours ($n = 0, 1, 2, \dots, 6$).

The absorption intensity of each component might be proportional to the probability for existence of each arrangement in the crystal. Concentration

ABSORPTION LINES IN TRANSITION METAL COMPLEXES

Figure 15. Splitting of the R lines under dilution of Cr^{3+} ions by Al^{3+} ions in guanidine chromium sulphate hexahydrate

dependence of absorption intensity is well accounted for if probabilities of these seven different arrangements are taken, under the assumption of the random distribution of Cr^{3+} ions over the crystal without preference to occupy the C_3 or C_{3v} symmetry sites. The splitting of 6 cm^{-1} between two neighbouring components results from the difference between the electric field strengths on the central ions for the two adjacent arrangements in Figure 16.

Figure 16. Model of arrangements of nearest neighbours of $[\text{M}(\text{H}_2\text{O})_6]^{3+}$ ions around the central $[\text{Cr}(\text{H}_2\text{O})_6]^{3+}$ ion in guanidine chromium sulphate hexahydrate. Open and shaded circles represent $[\text{Al}(\text{H}_2\text{O})_6]^{3+}$ and $[\text{Cr}(\text{H}_2\text{O})_6]^{3+}$ ions respectively

The shift of components linearly dependent on concentration may be explained by considering that a part of the electric field for Cr^{3+} sites results from the concentration dependent spontaneous polarization of the whole crystal.

I give sincere thanks to the Organizing Committee of the Conference for affording me the opportunity of presenting a plenary lecture in this honourable meeting and also to my collaborators in our laboratory for their eager and constant efforts.

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ABSORPTION LINES IN TRANSITION METAL COMPLEXES

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